

Low-Power, High-Speed CMOS Analog Switches

DESCRIPTION

The DG401, DG403, DG405 monolithic analog switches were designed to provide precision, high performance switching of analog signals. Combining low power (0.35 μ W, typ.) with high speed (t_{ON} : 75 ns, typ.), the DG401 series is ideally suited for portable and battery powered industrial and military applications.

Built on the Vishay Siliconix proprietary high-voltage silicon-gate process to achieve high voltage rating and superior switch on/off performance, break-before-make is guaranteed for the SPDT configurations. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to 30 V peak-to-peak when off. On-resistance is very flat over the full ± 15 V analog range, rivaling JFET performance without the inherent dynamic range limitations.

The three devices in this series are differentiated by the type of switch action as shown in the functional block diagrams.

FEATURES

- 44 V supply max. rating
- ± 15 V analog signal range
- On-resistance - $R_{DS(on)}$: 30 Ω
- Low leakage - $I_{D(on)}$: 40 pA
- Fast switching - t_{ON} : 75 ns
- Ultra low power requirements - P_D : 0.35 μ W
- TTL, CMOS compatible
- Single supply capability
- **Compliant to RoHS directive 2002/95/EC**



RoHS*
COMPLIANT

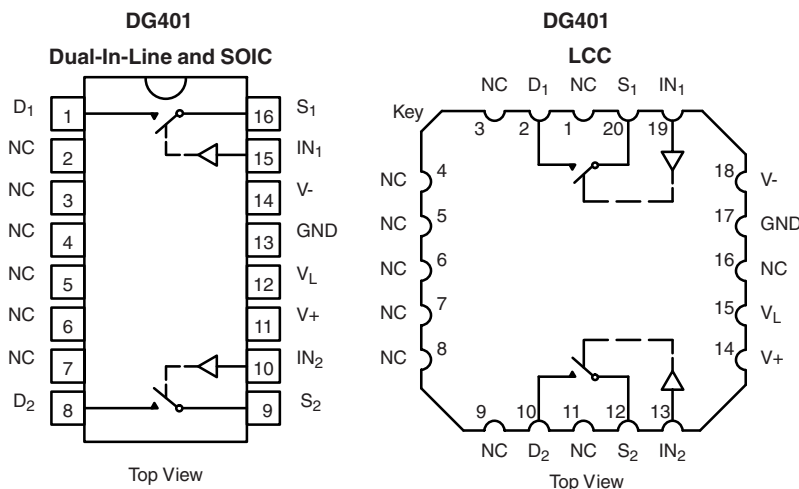
BENEFITS

- Wide dynamic range
- Break-before-make switching action
- Simple interfacing

APPLICATIONS

- Audio and video switching
- Sample-and-hold circuits
- Battery operation
- Test equipment
- Communications systems
- PBX, PABX

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Two SPST Switches per Package

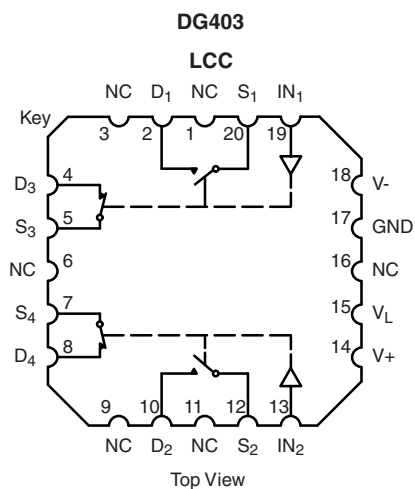
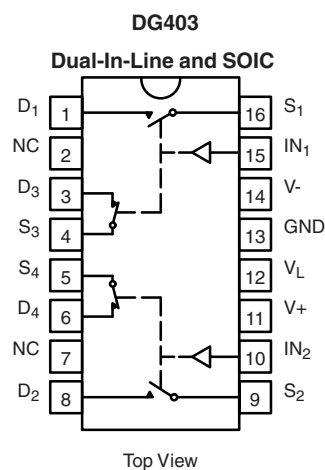
TRUTH TABLE

Logic	Switch
0	OFF
1	ON

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

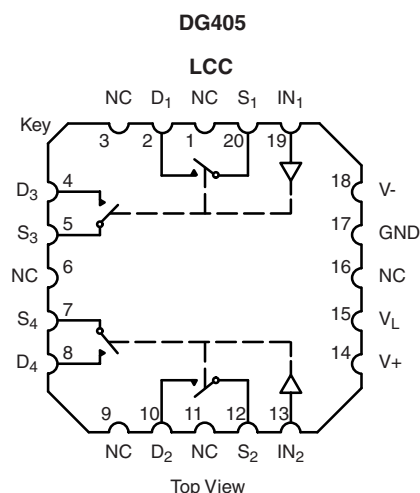
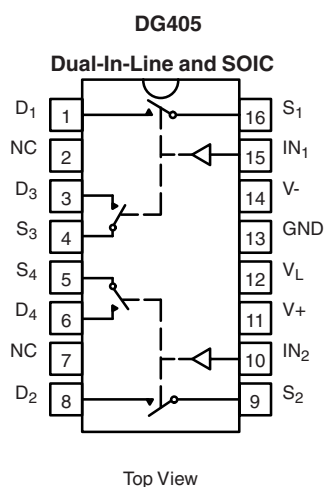


Two SPDT Switches per Package

TRUTH TABLE		
Logic	SW ₁ , SW ₂	SW ₃ , SW ₄
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V



Two DPST Switches per Package

TRUTH TABLE	
Logic	Switch
0	OFF
1	ON

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V



ORDERING INFORMATION		
Temp. Range	Package	Part Number
DG401		
- 40 °C to 85 °C	16-Pin Plastic DIP	DG401DJ DG401DJ-E3
	16-Pin Narrow SOIC	DG401DY DG401DY-T1 DG401DY-E3 DG401DY-T1-E3
DG403		
- 40 °C to 85 °C	16-Pin Plastic DIP	DG403DJ DG403DJ-E3
	16-Pin Narrow SOIC	DG403DY DG403DY-E3 DG403DY-T1 DG403DY-T1-E3
DG405		
- 40 °C to 85 °C	16-Pin Plastic DIP	DG405DJ DG405DJ-E3
	16-Pin Narrow SOIC	DG405DY DG405DY-E3 DG405DY-T1 DG405DY-T1-E3

ABSOLUTE MAXIMUM RATINGS			
Parameter		Limit	Unit
V+ to V-		44	V
GND to V-		25	
V _L		(GND - 0.3) to (V+) + 0.3	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current (Any Terminal) Continuous		30	mA
Current, S or D (Pulsed 1 ms, 10 % Duty)		100	
Storage Temperature	(DJ, DY Suffix)	- 65 to 125	°C
Power Dissipation (Package) ^b	16-Pin Plastic DIP ^c	450	mW
	16-Pin SOIC ^d	600	

Notes:

a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 6 mW/°C above 75 °C.

d. Derate 7.6 mW/°C above 75 °C.

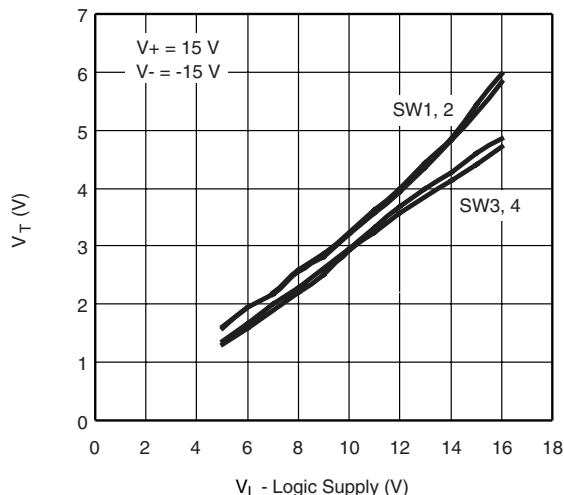
SPECIFICATIONS ^a							
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 15 V, V ₋ = - 15 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	V
Drain-Source On-Resistance	R _{DS(on)}	I _S = - 10 mA, V _D = ± 10 V V ₊ = 13.5 V, V ₋ = - 13.5 V	Room Full	30		45 55	Ω
Δ Drain-Source On-Resistance	ΔR _{DS(on)}	I _S = - 10 mA, V _D = ± 5 V, 0 V V ₊ = 16.5 V, V ₋ = - 16.5 V	Room Full	3		3 5	
Switch Off Leakage Current	I _{S(off)}	V ₊ = 16.5 V, V ₋ = - 16.5 V V _D = ± 15.5 V, V _S = ± 15.5 V	Room Hot	- 0.01	- 0.5 - 5	0.5 5	nA
	I _{D(off)}		Room Hot	- 0.01	- 0.5 - 5	0.5 5	
Channel On Leakage Current	I _{D(on)}	V ₊ = 16.5 V, V ₋ = - 16.5 V V _S = V _D = ± 15.5 V	Room Hot	- 0.04	- 1 - 10	1 10	
Digital Control							
Input Current V _{IN} Low	I _{IL}	V _{IN} under test = 0.8 V All Other = 2.4 V	Full	0.005	- 1	1	μA
Input Current V _{IN} High	I _{IH}	V _{IN} under test = 2.4 V All Other = 0.8 V	Full	0.005	- 1	1	
Dynamic Characteristics							
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF See Figure 2	Room	75		150	ns
Turn-Off Time	t _{OFF}		Room	30		100	
Break-Before-Make Time Delay (DG403)	t _D	R _L = 300 Ω, C _L = 35 pF	Room	35	5		
Charge Injection	Q	C _L = 10 nF V _{gen} = 0 V, R _{gen} = 0 Ω	Room	60			pC
Off Isolation Reject Ratio	OIRR	R _L = 100 Ω, C _L = 5 pF f = 1 MHz	Room	72			dB
Channel-to-Channel Crosstalk	X _{TALK}		Room	90			
Source Off Capacitance	C _{S(off)}	f = 1 MHz, V _S = 0 V	Room	12			pF
Drain Off Capacitance	C _{D(off)}		Room	12			
Channel On Capacitance	C _D , C _{S(on)}		Room	39			
Power Supplies							
Positive Supply Current	I ₊	V ₊ = 16.5 V, V ₋ = - 16.5 V V _{IN} = 0 or 5 V	Room Full	0.01		1 5	μA
Negative Supply Current	I ₋		Room Full	- 0.01	- 1 - 5		
Logic Supply Current	I _L		Room Full	0.01		1 5	
Ground Current	I _{GND}		Room Full	- 0.01	- 1 - 5		

Notes:

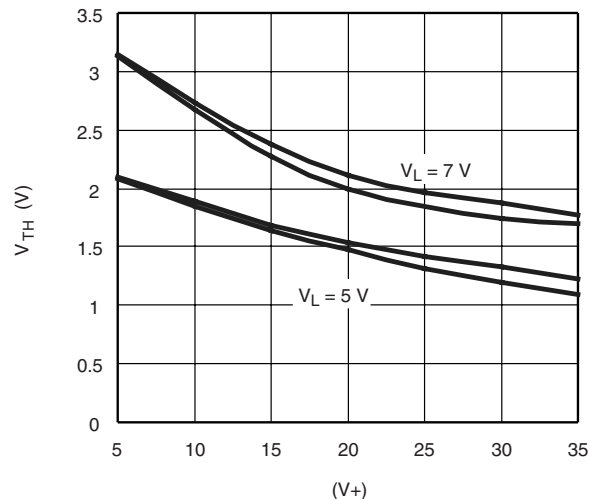
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

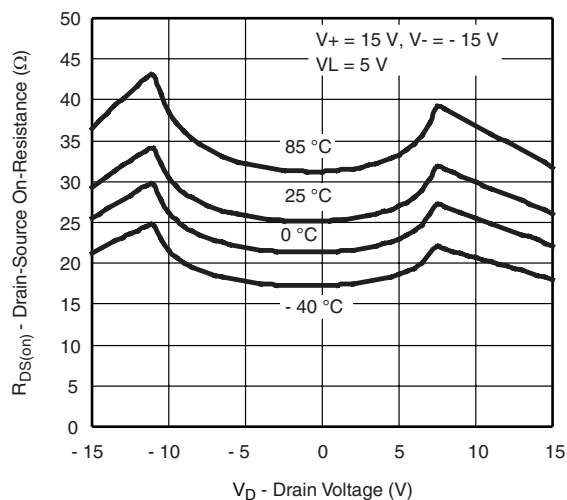
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



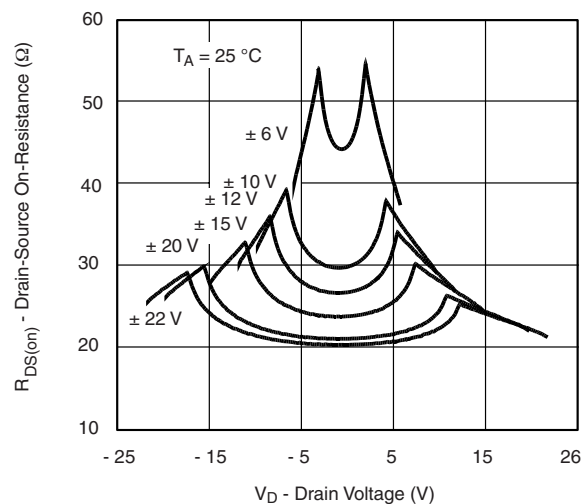
Input Switching Threshold vs. Logic Supply Voltage



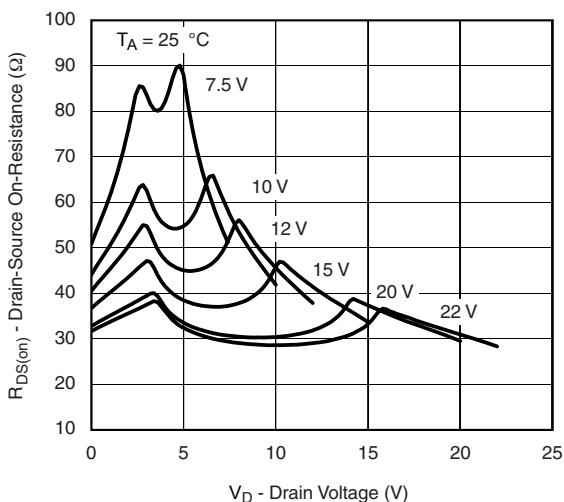
Input Switching Threshold vs. Supply Voltages



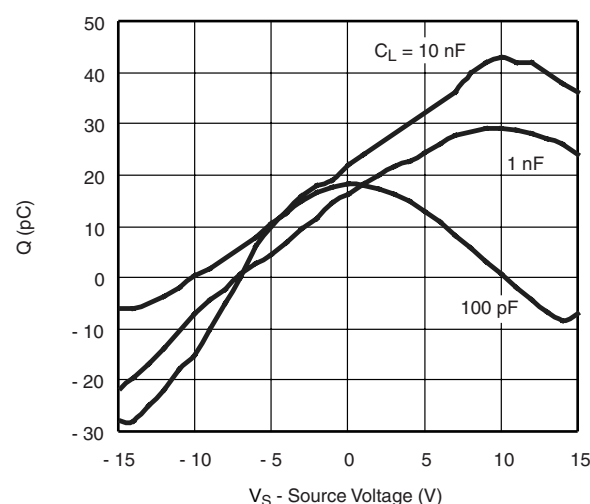
$R_{DS(on)}$ vs. V_D and Temperature



$R_{DS(on)}$ vs. V_D and Power Supply Voltage

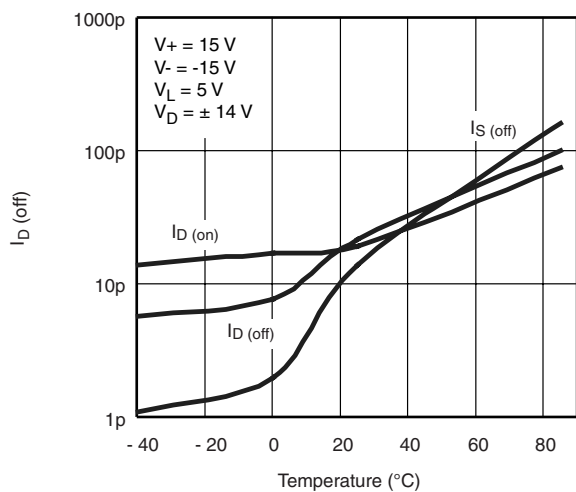


$R_{DS(on)}$ vs. V_D and Power Supply Voltage ($V_- = 0$ V)

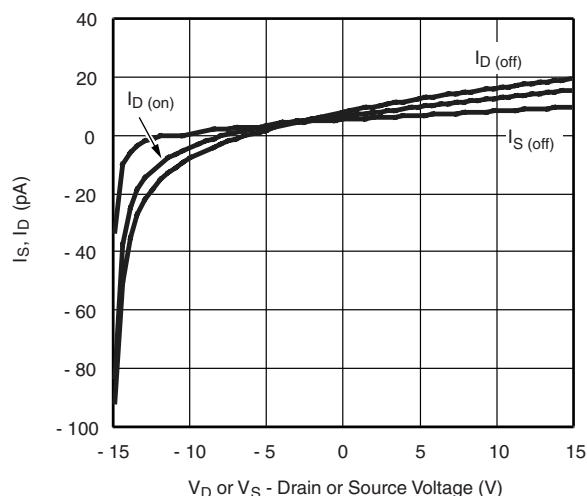


Charge Injection vs. Analog Voltage

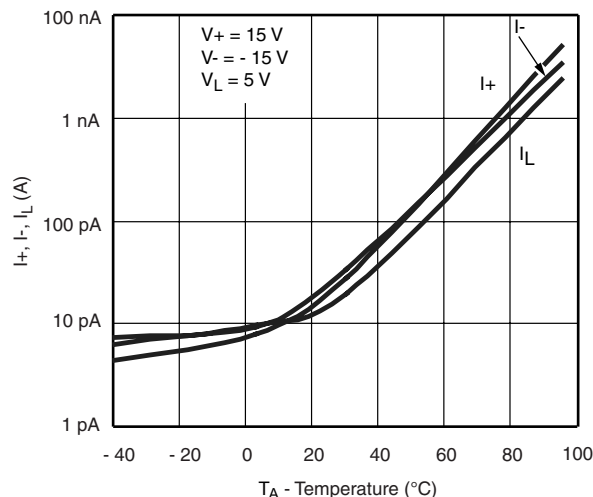
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



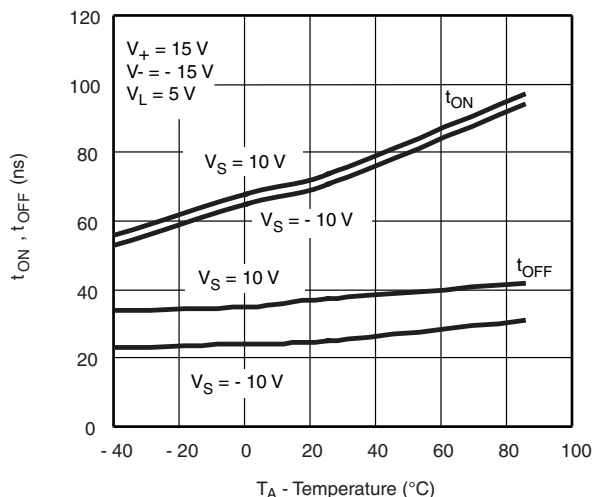
Leakage Current vs. Temperature



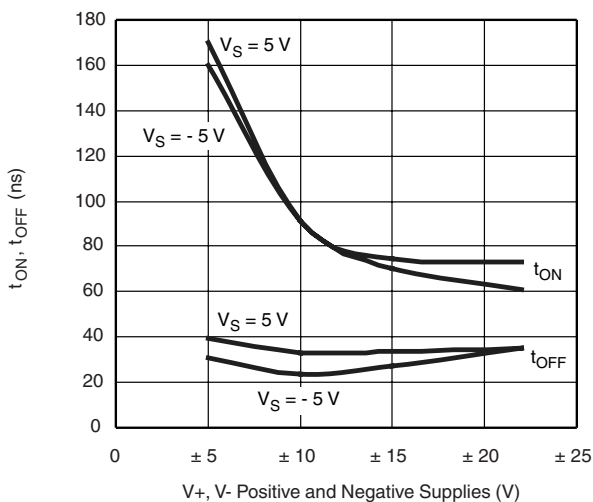
Leakage Current vs. Analog Voltage



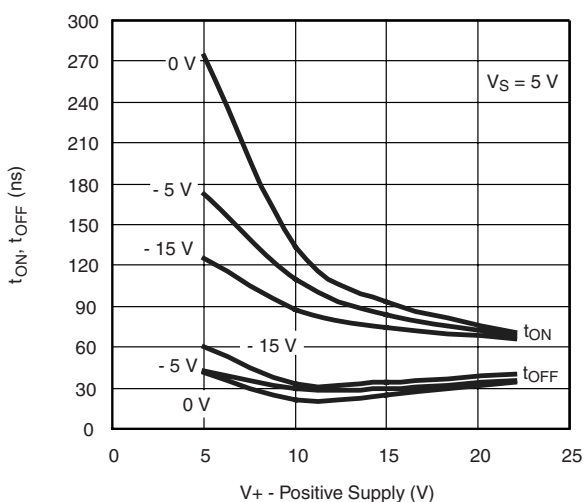
Supply Current vs. Temperature



Switching Time vs. Temperature*

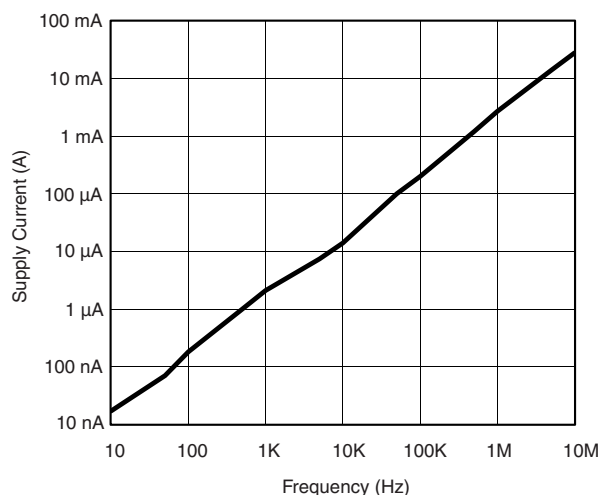
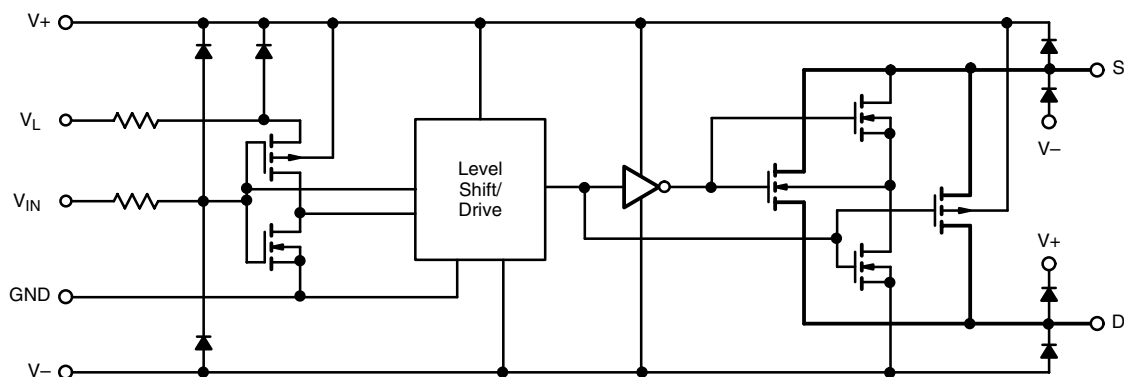


Switching Time vs. Power Supply Voltage*



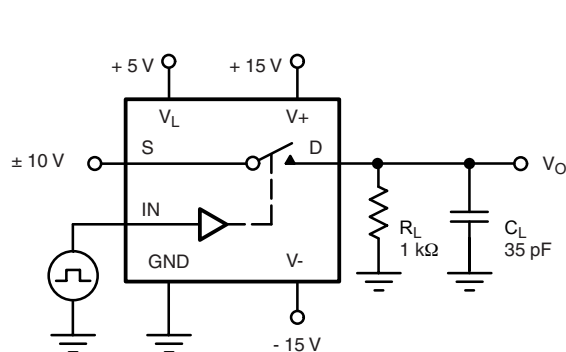
Switching Time vs. Positive Supply Voltage*

* Refer to Figure 2 for test conditions.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Supply Current vs. Switching Frequency
SCHEMATIC DIAGRAM Typical Channel

Figure 1.

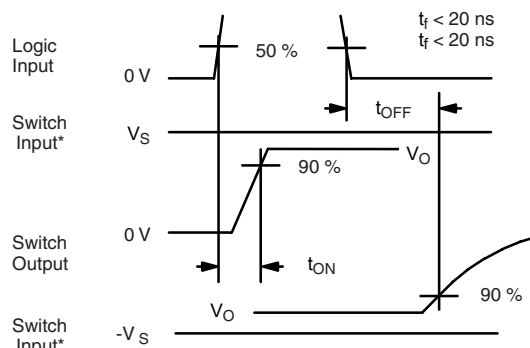
TEST CIRCUITS

V_O is the steady state output with the switch on. Feedthrough via switch capacitance may result in spikes at the leading and trailing edge of the output waveform.



C_L (includes fixture and stray capacitance)

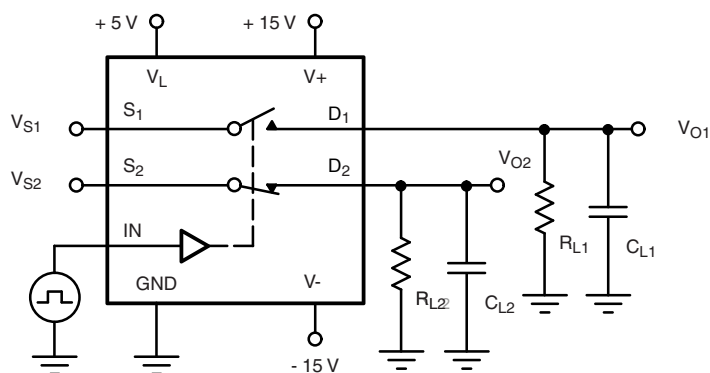
$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



* $V_S = 10\text{ V}$ for t_{ON} , $V_S = -10\text{ V}$ for t_{OFF}

Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 2. Switching Time



C_L (includes fixture and stray capacitance)

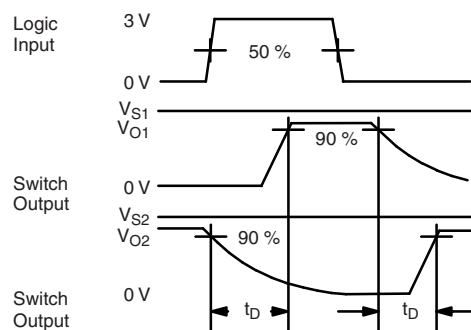


Figure 3. Break-Before-Make

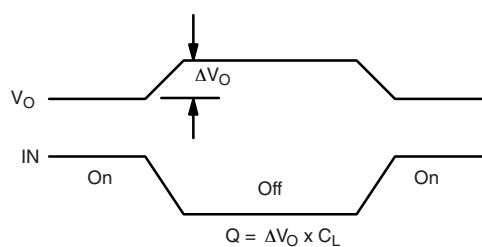
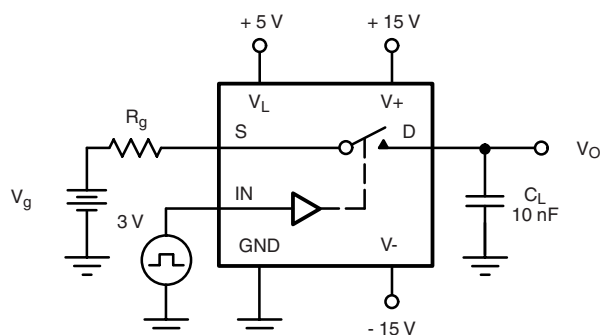
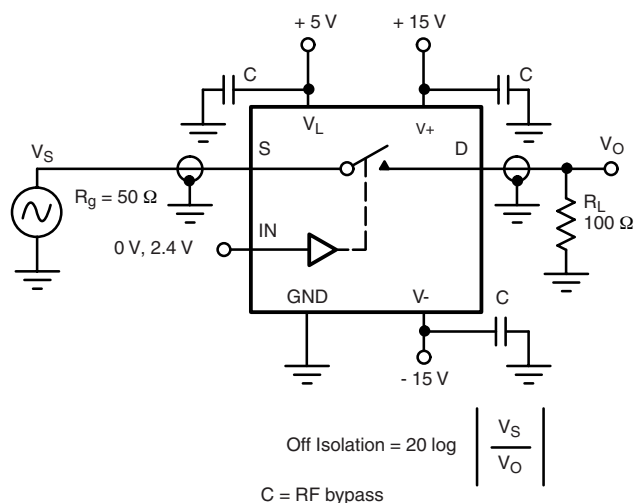
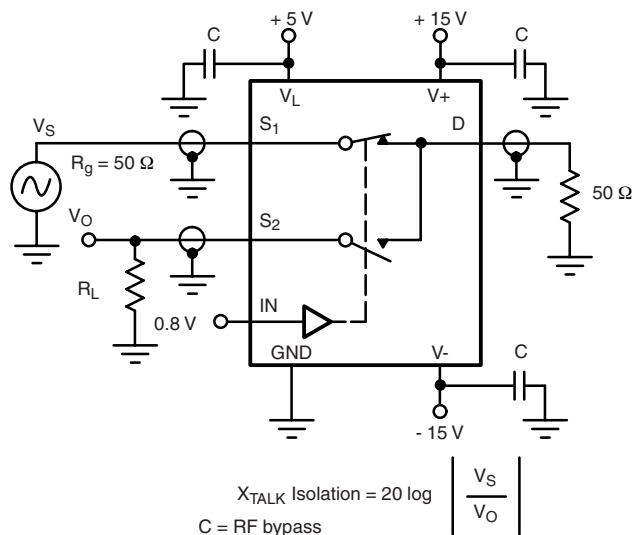
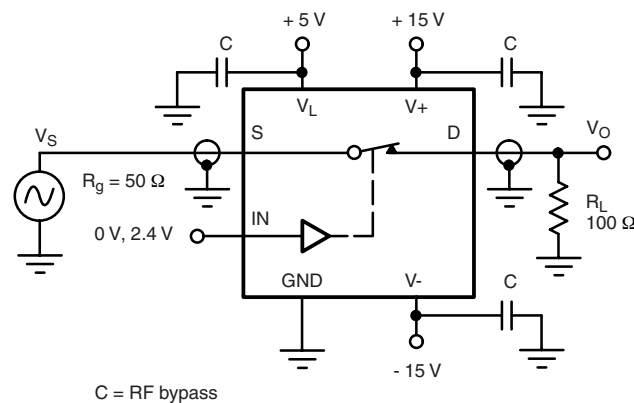
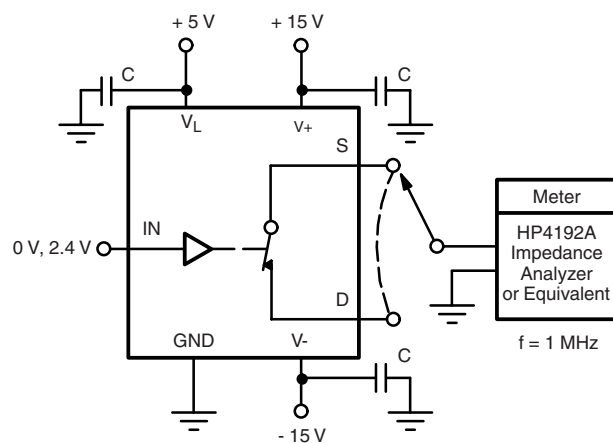


Figure 4. Charge Injection

TEST CIRCUITS

Figure 5. Off Isolation

Figure 7. Crosstalk

Figure 6. Insertion Loss

Figure 8. Capacitances

APPLICATIONS

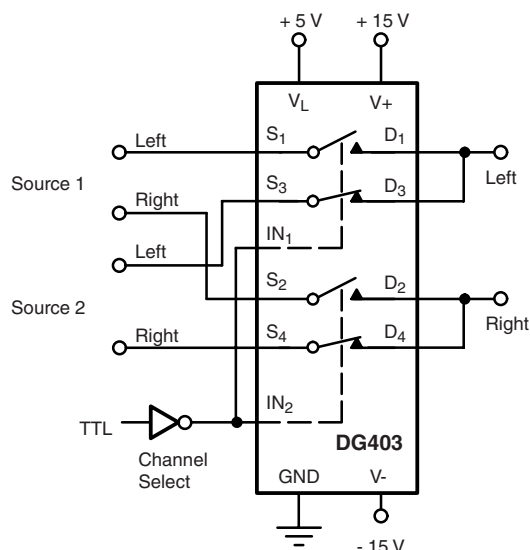


Figure 9. Stereo Source Selector

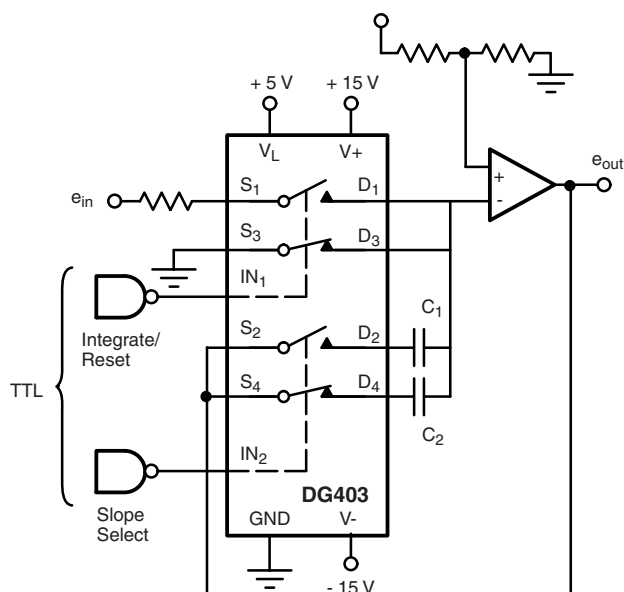


Figure 10. Dual Slope Integrator

Dual Slope Integrators:

The DG403 is well suited to configure a selectable slope integrator. One control signal selects the timing capacitor C_1 or C_2 . Another one selects e_{in} or discharges the capacitor in preparation for the next integration cycle.

Band-Pass Switched Capacitor Filter:

Single-pole double-throw switches are a common element for switched capacitor networks and filters. The fast switching times and low leakage of the DG403 allow for higher clock rates and consequently higher filter operating frequencies.

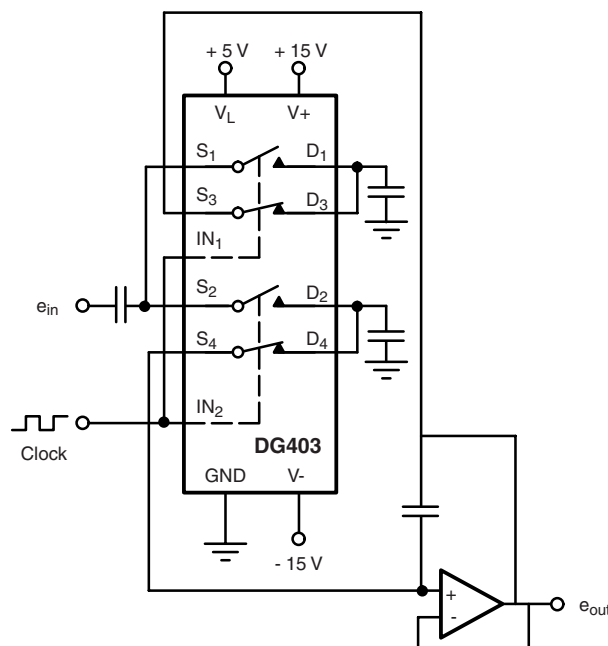
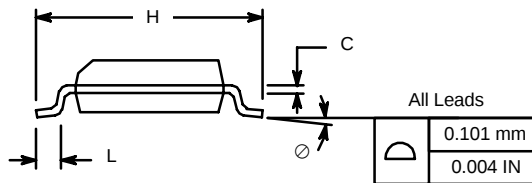


Figure 11. Band-Pass Switched Capacitor Filter



SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



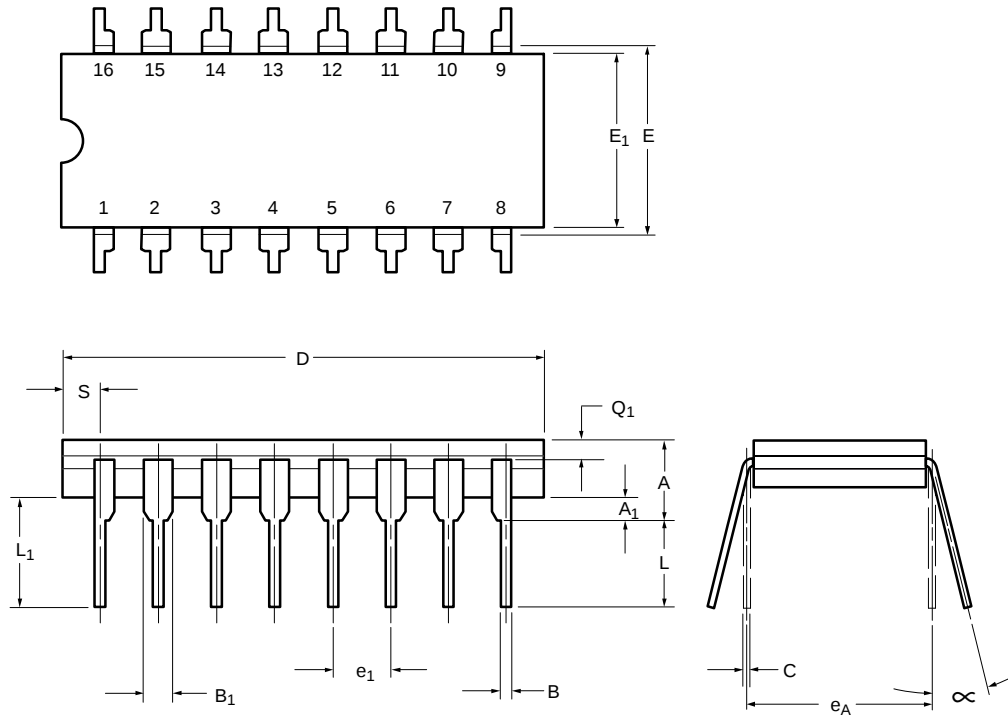
PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E₁	5.59	7.11	0.220	0.280
e₁	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482				



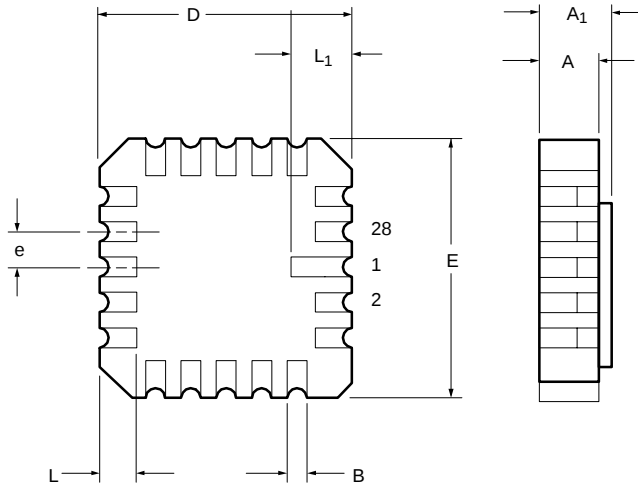
CERDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	4.06	5.08	0.160	0.200
A ₁	0.51	1.14	0.020	0.045
B	0.38	0.51	0.015	0.020
B ₁	1.14	1.65	0.045	0.065
C	0.20	0.30	0.008	0.012
D	19.05	19.56	0.750	0.770
E	7.62	8.26	0.300	0.325
E ₁	6.60	7.62	0.260	0.300
e ₁	2.54 BSC		0.100 BSC	
e _A	7.62 BSC		0.300 BSC	
L	3.18	3.81	0.125	0.150
L ₁	3.81	5.08	0.150	0.200
Q ₁	1.27	2.16	0.050	0.085
S	0.38	1.14	0.015	0.045
∞	0°	15°	0°	15°
ECN: S-03946—Rev. G, 09-Jul-01 DWG: 5403				



20-LEAD LCC



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.37	2.24	0.054	0.088
A₁	1.63	2.54	0.064	0.100
B	0.56	0.71	0.022	0.028
D	8.69	9.09	0.342	0.358
E	8.69	9.09	0.442	0.358
e	1.27 BSC		0.050 BSC	
L	1.14	1.40	0.045	0.055
L₁	1.96	2.36	0.077	0.093
ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5321				

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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<http://moschip.ru/get-element>

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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